

SPEC SHEET (FOR REFERENCE)	SHEET No.	Rev.	Page.
	G05087A	0	1 of 1

TYPE:6PT2403P3T * *

CHIP SIZE	1.29 * 0.94mm
WAFER SIZE	6inch
POSSIBLE DIE PER WAFER	12,640 pcs

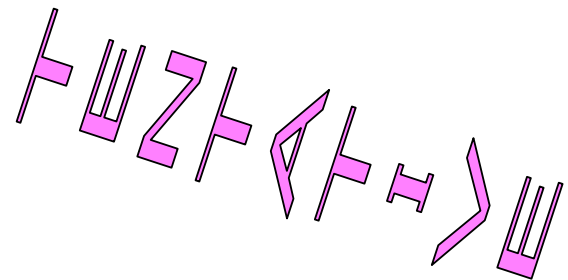
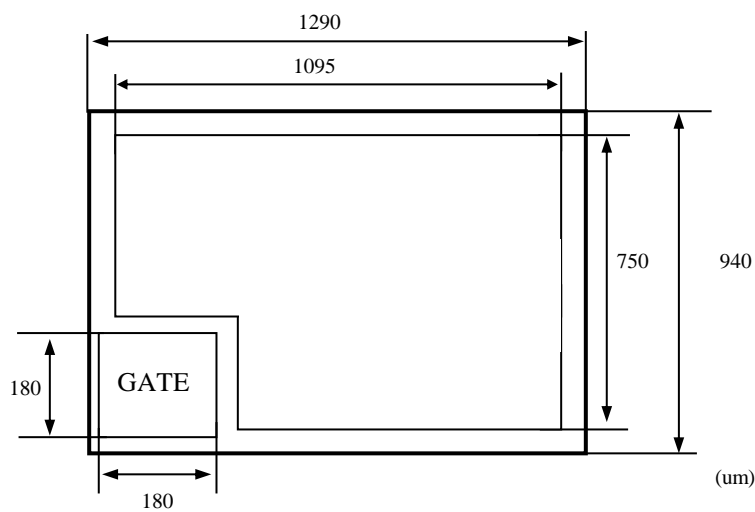
Maximum Ratings (Ta=25°C)

Characteristics	Symbol	Ratings	Unit
Drain-source voltage	V _{DSS}	-30	V
Gate-source voltage	V _{GSS}	±20	V

WAFER PROBING SPEC (Ta=25°C)

No	MODE	LIMIT				CONDITIONS
		MIN.	Typ	MAX.	UNIT	
1	IGSS			±10	uA	V _G S=±20.0V V _D S=0V
2	IDSS			-1	uA	V _D S=-30.0V V _G S=0V
3	BVDSS	-32			V	ID=-1mA
4	V _{TH}	-1.0		-2.0	V	ID=-250uA
5	RDS(on)		0.05	0.1	ohm	ID=-2.0A V _G S=-10.0V
6	VSD	-0.5	-0.8	-1.1	V	IS=-1A

※ Built-in ZD between Gate and Source.



NOTE: